

L Number	Hits	Search Text	DB	Time stamp
1	6570	silicide with (titanium platinum) and ((titanium with nitride) TiN)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/22 14:36
2	98	(silicide with (titanium platinum) and ((titanium with nitride) TiN) ) and electron with emitter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/22 15:05
3	215	(n-type same epitaxial with silicon) and electron with emitter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/22 15:11
9	20	(n-type same ((silicon with carbide) SiC!) same (phosphorus Nitrogen Vanadium)) and electron with emitter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/22 15:36
10	93	(n-type same ((silicon with carbide) SiC!) same (phosphorus P! Nitrogen N! Vanadium V!)) and electron with emitter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/22 15:36
11	187	(n-type same epitaxial with silicon same (arsenic As! phosphorus P! antimony Sb!)) and electron with emitter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/22 15:36
-	1882	(313/311,310,346).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/22 14:33
-	26	((313/311,310,346).CCLS.) and ((porous porosity) with (Silicon Si))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/16 13:30
-	200	emit\$5 and ((porous porosity) with (Silicon Si) same n?type)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/16 13:50
-	180	(emit\$5 and ((porous porosity) with (Silicon Si) same n?type) ) and @ad<20010430	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/16 13:50
-	66	electron with emit\$5 and ((porous porosity) with (Silicon Si) same n?type)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 08:47
-	58	(electron with emit\$5 and ((porous porosity) with (Silicon Si) same n?type) ) and @ad<20010430	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/16 14:31
-	59	field with emit\$5 and ((porous porosity) with (Silicon Si) same n?type)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/16 14:31

-	51	(field with emit\$5 and ((porous porosity) with (Silicon Si) same n?type) ) and @ad<20010430	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/16 14:34
-	4	((("5652474") or ("5894189"))).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/16 14:34
-	66	(electron with emit\$5) and ((porous porosity) with (Silicon Si) same n\$7?type)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 10:20
-	3216	(313/309,336,351;445/46,50,51).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 10:20
-	16	((313/309,336,351;445/46,50,51).CCLS.) and ((porous porosity) with (Silicon Si) same n\$7?type)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 10:21
-	12	"845845"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 13:57
-	2692	"n+" with dop\$4 with (Silicon si)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 13:58
-	220	("n+" with dop\$4 with (Silicon si)) and (("100" with crystal\$) ("110" with crystal\$))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 15:11
-	95	((("n+" with dop\$4 with (Silicon si)) and (("100" with crystal\$) ("110" with crystal\$)) ) and emit\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/17 15:19
-	8	"5990605"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/18 07:46
-	2	5296388.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/18 07:46